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Diodes Incorporated DMN3033LSD-13

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DMN3033LSD

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

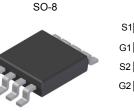
V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
30V	20mΩ @ V _{GS} = 10V	6.9A
	27mΩ @ V _{GS} = 4.5V	5.8A

Description

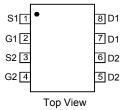
This MOSFET has been designed to minimize the on-state resistance $(R_{DS(on)})$ and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters



Top View



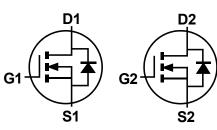
Internal Schematic

Features

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching SpeedLow Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight: 0.072grams (approximate)



N-channel MOSFET

N-channel MOSFET

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3033LSD-13	SO-8	2,500/Tape & Reel

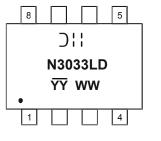
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

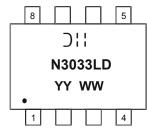
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

Marking Information



Chengdu A/T Site



Shanghai A/T Site





DMN3033LSD

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V _{DSS}	30	V
Gate-Source Voltage			V _{GSS}	±20	V
Drain Current (Note 5)	Steady State	T _A = +25°C T _A = +70°C	ID	6.9 5.8	A
Pulsed Drain Current (Note 6)			I _{DM}	30	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	2	W
Thermal Resistance, Junction to Ambient	R _{0JA}	62.5	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

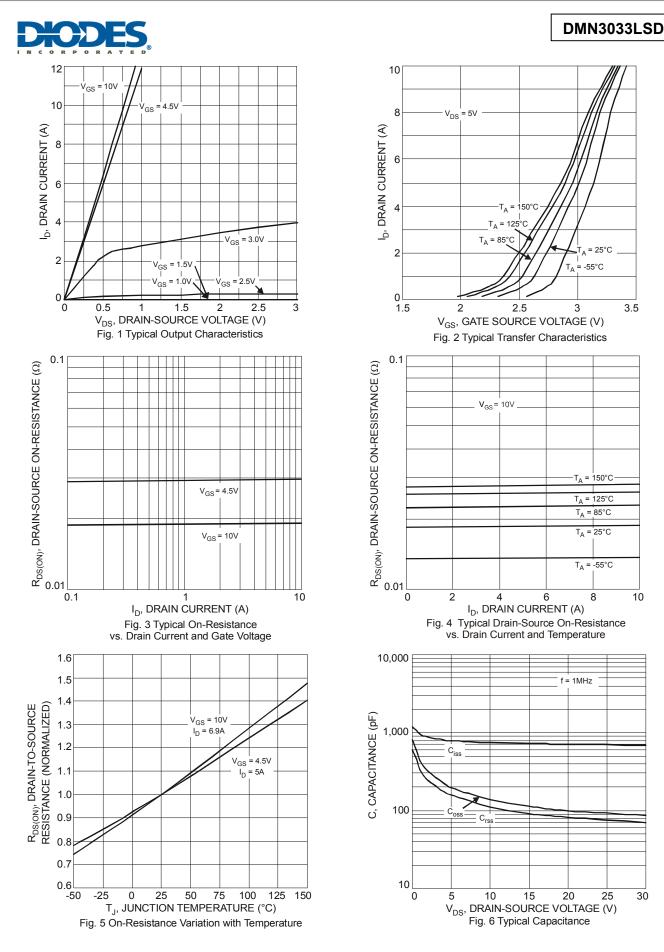
		0				1	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	30	—	—	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	IDSS	_		100	nA	V _{DS} = 30V, V _{GS} = 0V	
Gate-Source Leakage				±100	nA	V_{GS} = ±20V, V_{DS} = 0V	
Gale-Source Leakage	I _{GSS}	_		1	μA	$V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	1	_	2.1	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Statia Drain Sauras On Desistance			13	20	mΩ	V _{GS} = 10V, I _D = 6.9A	
Static Drain-Source On-Resistance	R _{DS (ON)}		22	27	11122	V _{GS} = 4.5V, I _D = 5A	
Forward Transconductance	g fs	_	7	_	S	V _{DS} =5V, I _D = 6.9A	
Diode Forward Voltage (Note 7)	V _{SD}	0.5		1.2	V	V _{GS} = 0V, I _S = 1A	
DYNAMIC CHARACTERISTICS							
Input Capacitance	Ciss	_	725	_	pF		
Output Capacitance	Coss	_	114	_	pF	V _{DS} = 15V, V _{GS} = 0V f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	92	_	pF		
Gate Resistance	R _G	_	0.89	_	Ω	V_{GS} = 0V, V_{DS} = 0V, f = 1MHz	
SWITCHING CHARACTERISTICS							
Total Gate Charge	0	_	- 6.4 13	_	nC	V _{GS} = 4.5V, V _{DS} = 15V, I _D =5A	
Total Gate Charge	Qg					V_{GS} = 10V, V_{DS} = 15V, I_{D} = 6.9A	
Gate-Source Charge	Q _{gs}		1.9	_	nC	V_{GS} = 4.5V, V_{DS} = 15V, I_{D} = 6.9A	
Gate-Drain Charge	Q _{gd}		3.2	-	nC	V _{GS} = 4.5V, V _{DS} = 15V, I _D = 6.9A	
Turn-On Delay Time	t _{d(on)}	_	11	_	ns		
Turn-On Rise Time		_	7	_	ns	V _{DD} = 15V, V _{GS} = 10V,	
Turn-Off Delay Time	t _{d(off)}		63	—	ns	$R_D = 1.8\Omega, R_G = 6\Omega$	
Turn-Off Fall Time	t _f	_	30	—	ns		

Notes:

5. Device mounted on 2 oz. Copper pads on FR-4 PCB with R_{6JA} = 62.5°C/W

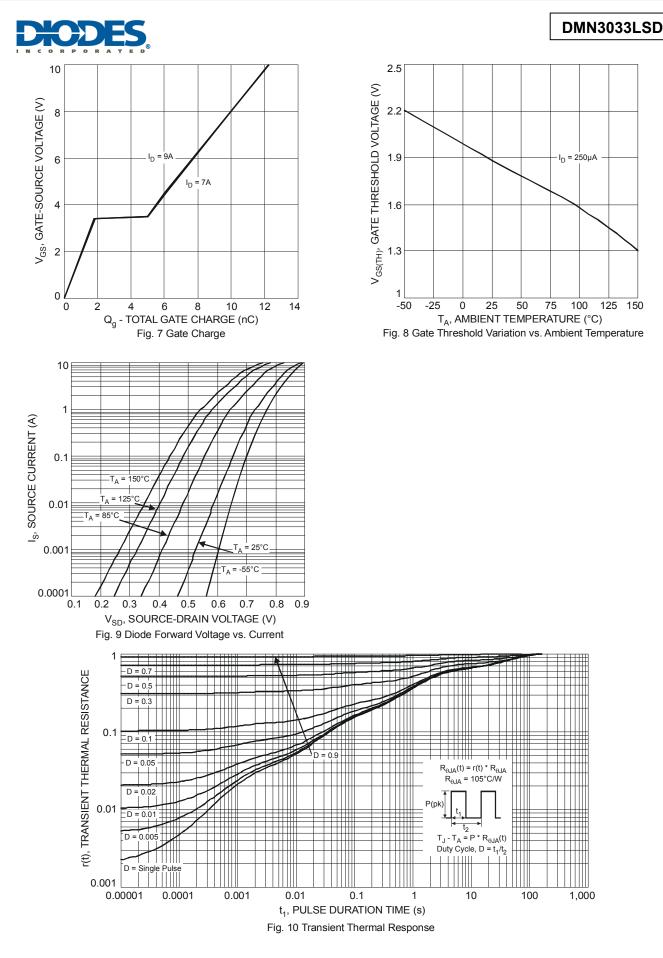
Pulse width ≤10µS, Duty Cycle ≤1%.
Short duration pulse test used to minimize self-heating effect.





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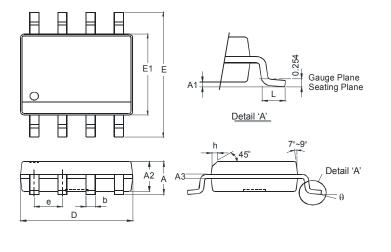




DMN3033LSD

Package Outline Dimensions

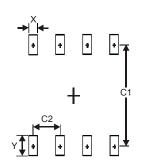
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SO-8					
Dim	Min	Max			
Α	-	1.75			
A1	0.10	0.20			
A2	1.30	1.50			
A3	0.15	0.25			
b	0.3	0.5			
D	4.85	4.95			
ш	5.90	6.10			
E1	3.85	3.95			
е	1.27 Typ				
h	- 0.35				
L	0.62	0.82			
θ	0°	8°			
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.60
Y	1.55
C1	5.4
C2	1.27





DMN3033LSD

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